Science Bulletin 68 (2023) 1611-1615



Contents lists available at ScienceDirect

Science Bulletin



journal homepage: www.elsevier.com/locate/scib

Short Communication

Production of single-crystal Cu plates by electrodeposition on high-index Cu foils

Xingguang Li^a, Zhihong Zhang^{b,*}, Zhibin Zhang^a, Jinzong Kou^{c,d}, Muhong Wu^{c,e,f}, Mengze Zhao^a, Ruixi Qiao^a, Zhiqiang Ding^c, Zhiqiang Zhang^c, Fang Liu^a, Xiaonan Yang^b, Dingxin Zou^g, Xinqiang Wang^a, Peng Gao^e, Ying Fu^c, Enge Wang^{c,e,h,*}, Kaihui Liu^{a,c,e,*}

^a State Key Laboratory for Mesoscopic Physics, Frontiers Science Centre for Nano-optoelectronics, School of Physics, Peking University, Beijing 100871, China

^c Songshan Lake Materials Laboratory, Dongguan 523808, China

^d Beijing National Laboratory for Condensed Matter Physics, Institute of Physics, Chinese Academy of Sciences, Beijing 100190, China

^e International Centre for Quantum Materials, Collaborative Innovation Centre of Quantum Matter, Peking University, Beijing 100871, China

^f Interdisciplinary Institute of Light-Element Quantum Materials and Research Centre for Light-Element Advanced Materials, Peking University, Beijing 100871, China

^g Shenzhen Institute for Quantum Science and Engineering, Southern University of Science and Technology, Shenzhen 518055, China

^h School of Physics, Liaoning University, Shenyang 110036, China

ARTICLE INFO

Article history: Received 10 March 2023 Received in revised form 24 May 2023 Accepted 21 June 2023 Available online 24 June 2023

 $\ensuremath{\textcircled{\circ}}$ 2023 Science China Press. Published by Elsevier B.V. and Science China Press. All rights reserved.

Massive production of single-crystal metals has been a long pursuit in materials science and engineering due to their superior electrical, thermal and mechanical performances compared with polycrystalline ones. Single-crystal metal ingots could be traditionally fabricated by the Czochralski technique, and large-size singlecrystal metal foils (with thickness limited to several tens of micrometers) have been recently prepared by the designed thermal annealing of polycrystalline ones [1–4]. However, for the thicker single-crystal metal foils or plates, the economic and efficient preparation has not yet been achieved. In principle, epitaxial electrodeposition of metal on single-crystal substrates provides an economic and efficient way to achieve highly ordered metal films [5–9]. However, as the electrodeposition goes on, the number of defects increases and lattice twinning occurs more easily, which leads to the structure transition to polycrystals [5,6]. Consequently, epitaxial electrodeposition on single-crystal substrate was reported to only reach several-micrometer-thick single-crystal films, even the epilayer and the substrate are of the same lattice structure [7–9]. Hence, a new strategy needs to be developed to regulate the electrodeposition process for the preparation of thick single crystals.

In this work, we demonstrated the electrodeposition of singlecrystal Cu with thickness up to millimeters on high-index singlecrystal Cu foils. The electrodeposition was carried out with polycrystalline Cu plates as anodes and high-index single-crystal Cu foil $(\sim 25 \,\mu\text{m}, \text{obtained by the designed thermal annealing [4]})$ as cathode (Fig. 1a, see Method in Supplementary materials and Fig. S1 (online) for more details). Fig. 1b shows a \sim 100 μ m-thick electrodeposited Cu plate with single-crystal Cu(211) foil as cathode (the thickness of the deposition layer on each side, Δt , is ~38 μm). We first used X-ray diffraction (XRD) to characterize the crystal orientation of the deposition layer. The XRD 2θ -scan results show that the out-of-plane orientation of the deposition layer is the same as the Cu(211) substrate (Fig. 1c). In the XRD azimuthal off-axis ϕ scan, only one peak corresponding to Cu(200) was observed, indicating the single-crystal structure without in-plane rotation (inset in Fig. 1c). Electron back-scattered diffraction (EBSD) was also carried out and uniform colors of the inverse pole figure maps in the Z and Y directions (IPF Z and IPF Y) demonstrate the deposition layer is indeed a single crystal (Fig. 1d). The atomic resolved high angle annular dark field scanning transmission electron microscopy (STEM) image confirms the lattice structure of the Cu(211) (Fig. 1e). All above results have verified that the deposition layer on Cu(211) is single-crystal.

We also characterized the electrical and mechanical properties of the single-crystal Cu plates to demonstrate their single-crystal nature and evaluate their quality. As shown in Fig. 1f, our prepared

* Corresponding authors.

2095-9273/© 2023 Science China Press. Published by Elsevier B.V. and Science China Press. All rights reserved.

^b Beijing Advanced Innovation Center for Materials Genome Engineering, Beijing Key Laboratory for Magneto-Photoelectrical Composite and Interface Science, State Key Laboratory for Advanced Metals and Materials, University of Science and Technology Beijing, Beijing 100083, China

E-mail addresses: zhzhang@ustb.edu.cn (Z. Zhang), egwang@pku.edu.cn Of the nature



Fig. 1. (Color online) Electrodeposition of single-crystal Cu plates and their structural and properties characterizations. (a) Schematics of electrodeposition on single-crystal Cu foil, where the polycrystalline Cu plates are used as anodes and high-index single-crystal Cu foil as cathode. (b) Photograph of the electrodeposited Cu plate. (c) XRD 2θ scan spectra for the Cu(211) substrate and the electrodeposited Cu plate, respectively. Inset, azimuthal off-axis ϕ scan spectrum for the electrodeposited Cu plate with only one peak corresponding to Cu(200). (d) Representative EBSD IPF maps of the electrodeposited plate in the *Z* (top, along the thickness direction) and Y (bottom) directions, respectively. (e) Atomically resolved STEM image of the electrodeposited plate. (f) Room temperature electrical conductivity of single-crystal Cu plates and four kinds of commercial electrolytic polycrystalline products. (g) Typical tensile stress-strain curves for the single-crystal Cu plate and two kinds of commercial electrolytic polycrystalline products. The thickness of the all specimens in (f, g) is of ~100 µm. (h) Fatigue performance for our electrodeposited single-crystal and polycrystalline Cu with different thicknesses, and four kinds of commercial electrolytic polycrystalline Cu products (~100 µm thick).

single-crystal samples have the highest electrical conductivity up to 103.2% of international annealed copper standard (IACS) compared with those of the commercial polycrystalline ones (typically 98%–100% IACS). The electrical conductivity enhancement originates from the absence of grain boundaries in single crystals, which reduces the electrons scattering by disordering and surface roughness [10].

We then compared the mechanical properties of the electrodeposited single-crystal Cu to the commercial polycrystalline ones. Before testing, all samples (\sim 100 µm) were subjected to the same thermal annealing process. The microstructures of 4 kinds of polycrystalline Cu after thermal annealing were characterized by EBSD, showing coarse grains with the size of several hundred micrometers and various crystallographic orientations (Fig. S2 online). Tensile tests were first carried out and representative tensile stress-strain curves for different samples are shown in Fig. 1g. The tensile test of the electrodeposited single-crystal sample was conducted along its <112> direction (the crystallographic direction was determined by EBSD characterization, as shown in Fig. S3 online), and it exhibited excellent ductility that the elongationto-fracture was as high as 108%, about 4 times of those of commercial ones. This is because in coarse-grain metal polycrystals, the uneven deformation between grains is difficult to coordinate, and cracks may form at the grain boundaries and lead to fracture easily, displaying inferior plasticity compared to the single crystal.

In terms of yield strength and ultimate tensile strength, there is no obvious difference between our prepared single-crystal samples and commercial ones for little grain boundary strengthening in coarse-grains polycrystalline Cu foils [11]. As for elasticity, due to the small specimens and small elastic strain of Cu (<5‰), it is extremely difficult to measure the displacement accurately in the elastic deformation region in the tensile test, leading to large error in calculating Young's modulus. But under the same test conditions, the obtained Young's modulus of single crystal is smaller than that of polycrystals, which can be ascribed to the anisotropy of single crystal [12].

The fatigue performances of our prepared samples were also evaluated (see Methods section in Supplementary materials online for more details). As shown in Fig. 1h, the numbers of cycles to failure follow similar trends for both the single-crystal and polycrystalline samples as their thickness increases, where they first climb up and then decline with the reflection point at the thickness of 60–70 μ m. Thinner samples have better flexibility, while their fracture strength is also lower. Thus when the thickness of the sample is small enough, their folding endurance performance starts to degrade [13]. Obviously the single-crystal samples have much better fatigue performance than the polycrystalline ones in the whole thickness range. In addition, we tested the fatigue performance of commercial samples (~100 μ m) and obtained similar results to our prepared polycrystalline samples.

To illustrate the mechanism of epitaxial electrodeposition of single-crystal Cu, we compare the different deposition behaviors on Cu(111) and Cu(211) in Fig. 2a. The surface of Cu(111) can be considered to have atomic flatness and the epitaxial deposition occurs by the two-dimensional (2D) nucleation and threedimensional island growth [14]. During the process, the nuclei with parallel and anti-parallel orientations may form due to the small energy difference on (111) plane (Fig. S4 online) [5]. Meantime when the islands meet, they cannot always merge together perfectly, leading to faults formation, which may further induce the lattice twinning and lead to twin crystal formation (Fig. 2a, upper panel). On the other hand, the deposited Cu atoms could directly diffuse to the atomic step edges on Cu(211) and attach on them and there is no nucleation stage during the electrodeposition on Cu(211) [15]. The interaction between Cu atoms and the step edges is much stronger, under which the Cu atoms could order themselves to duplicate the lattice arrangement of the substrate completely, which is the most energetically favorable. Although under our electrodeposition condition, the deposited Cu also follows the island growth, faults formation is less possible in such step-guided island growth mode (Fig. 2a, lower panel). The distinct island morphologies and growth behaviors on Cu(111) and Cu(211) at early deposition stage shown in scanning electron microscopy (SEM) images (Fig. S5 online) confirm this step-guided island growth and the advantageous effects of Cu(211) surface atomic steps on the epitaxial electrodeposition. Furthermore, SEM images taken when the samples were tilted by 70° show that the deposition layer on Cu(211) has a smoother surface compared to that on Cu (111) (Fig. 2b), which may also benefit from the step-guided deposition. The detailed mechanism needs further theoretical exploration and it should provide a new direction to produce low-profile electrolytic copper foil.

To consolidate the robust single-crystal duplication behavior during the whole electrodeposition process, we also conducted the EBSD characterization of the cross section of the electrodeposited Cu plate (145 μ m) with Cu(211) as substrate. The uniform contrast in the vicinity of the Cu(211) surface and the purple color across the entire thickness in the IPF mapping along *Y* direction demonstrate that the deposition layers are single-crystal and have the same lattice orientation as the substrate (Fig. 2c, d).

We further tried to prepare thicker Cu plates. Surprisingly, as the thickness is up to ~600 μ m, the Cu plate still remains to be single-crystal, indicating by the single orientation in the (100) pole figures (Fig. 2e, upper panel) as well as the IPF mapping along *Z* and *Y* direction and the XRD results (Fig. S6a–c online). On the other hand, when using Cu(111) as substrate, as the total thickness of the Cu plate increases, twin crystals and polycrystals will appear sequentially in the structures of electrodeposited layers (Fig. 2e lower panel and Fig. S6d–i online). Actually, the twinning already occurs in the 50 µm-thick Cu(111) plate.

Lastly, we investigate what is the maximum thickness of the single crystals that can be prepared on single-crystal Cu substrates with atomic steps on the surface. The transition from single crystal to twin- or polycrystals can be ascribed to the cumulation of defects during the epitaxial electrodeposition [5,6]. Thus, reducing defects formation can effectively increase the thickness of single-crystal deposition. From this point, we speculate that the surface quality of single-crystal Cu substrate, current density and purity of plating solution may determine the maximum thickness. We conducted controlled experiments to show the effects of the substrate surface quality, current density and purity of electrolyte on the maximum thickness. The results demonstrate poorer substrate quality, higher current density and/or lower-purity electrolyte would lead to easier transition from single crystal to polycrystals, and largely reduced thickness of single crystal (Fig. S7 online). By consistent efforts to optimize these experimental conditions, currently we have obtained a single crystal with thickness of \sim 3.3 mm on a vicinal Cu(110) substrate, which also has the surface with atomic steps. This maximum thickness is determined by our current experimental conditions and might be much larger in a more suitable electrodeposition environment.

In principle, this step-guided single-crystal duplication should in principle be applicable to the electrodeposition of Cu on other high-index Cu single crystal as well. Here we present three examples in Fig. 2f–h, with EBSD results verifying the single crystallinity of the Cu plates (each with thickness of ~100 μ m), proving the validity of our proposed robust single-crystal duplication mechanism.

In summary, we have demonstrated the step-guided singlecrystal duplication on high-index Cu, where the step edges interact with electrodeposited Cu atoms and guide them to position at the intended sites, to prepare large-size thick single-crystal Cu plates by electrodeposition. The obtained single-crystal Cu plates exhibit obvious improvement in the electrical conductivity, ductility and fatigue performance compared with the commercial electrodeposited polycrystalline ones. With these superior properties, we anticipate that our prepared single-crystal Cu plates may have potentials in high-speed and high-power electric applications. More importantly, the proposed mechanism of step-guided single-crystal duplication may also be suitable to produce other metal single crystals.

Conflict of interest

The authors declare that they have no conflict of interest.



Fig. 2. (Color online) Step-guided single-crystal duplication on high-index single-crystal Cu substrate. (a) Schematics of the different deposition behaviors on Cu(111) and Cu (211). (b) The distinct surface morphologies of electrodeposited Cu on Cu(111) (top, ~120 μ m-thick) and Cu(211) (bottom, ~130 μ m-thick) substrates, respectively. The cross-sectional SEM (c) and corresponding EBSD IPF Y map (d) of the electrodeposited Cu(211) plate (~145 μ m-thick). The normal direction of the IPF Y map is the same as the thickness direction of the electrodeposited foil. (e) Crystal structure evolution of the electrodeposited layers on Cu(211) and Cu(111) substrates as the electrodeposite thickness direction) and Y (bottom) directions of the electrodeposited Cu single-crystal plates (~100 μ m-thick) with the facet indices of (355), (221), and (331), respectively.

Acknowledgments

This work was supported by the Key R&D Program of Guangdong Province (2020B010189001 and 2019B010931001), the National Natural Science Foundation of China (52025023, 92163206, 51991342, 52021006, 52172035, and 52202161), the Strategic Priority Research Program of Chinese Academy of Sciences (XDB33000000), the National Key R&D Program of China (2021YFA1400502, 2021YFB3200303, and 2021YFA1400201), Guangdong Major Project of Basic and Applied Basic Research (2021B0301030002), and the Fundamental Research Funds for the Central Universities (06500235). Muhong Wu acknowledges support from the National Program for Support of Top-notch Young Professionals. We acknowledge the Electron Microscopy Laboratory in Peking University for the use of electron microscopy.

Author contribution

Kaihui Liu, Zhihong Zhang, and Enge Wang conceived and supervised the project. Xingguang Li and Zhiqiang Zhang took the

X. Li et al.

electrodeposition of Cu. Zhibin Zhang, Mengze Zhao, Muhong Wu, Ying Fu, and Dingxin Zou prepared the single-crystal Cu foils. Xingguang Li and Zhihong Zhang carried out the SEM and EBSD characterizations. Ruixi Qiao, Xiaonan Yang, and Peng Gao took the TEM characterization. Xingguang Li, Zhibin Zhang, Fang Liu, and Xinqiang Wang performed the XRD measurement. Xingguang Li, Jinzong Kou, and Zhiqiang Ding carried out the electrical and mechanical properties measurements. Zhihong Zhang, Xingguang Li, and Kaihui Liu performed the analysis and wrote the paper, and all the authors reviewed the paper.

Appendix A. Supplementary materials

Supplementary materials to this short communication can be found online at https://doi.org/10.1016/j.scib.2023.06.023.

References

- Uecker R. The historical development of the czochralski method. J Cryst Growth 2014;401:7–24.
- [2] Xu X, Zhang Z, Dong J, et al. Ultrafast epitaxial growth of metre-sized singlecrystal graphene on industrial cu foil. Sci Bull 2017;62:1074–80.
- [3] Jin S, Huang M, Kwon Y, et al. Colossal grain growth yields single-crystal metal foils by contact-free annealing. Science 2018;362:1021–5.
- [4] Wu M, Zhang Z, Xu X, et al. Seeded growth of large single-crystal copper foils with high-index facets. Nature 2020;581:406–10.
- [5] de Cusminsky JB. The role of stacking fault energy in metal electrodeposition. Scripta Metallurgica 1976;10:1071–3.
- [6] Kozlov VM, Bicelli LP. Formation of structural defects during metal electrocrystallization. J Cryst Growth 1996;165:421–8.
- [7] de Cusminsky JB, Wilman H. Growth and structure of single-crystal electrodeposits of copper; a systematic electron-diffraction study. Electrochimi Acta 1972;17:237–46.
- [8] Kelso MV, Tubbesing JZ, Chen Q, et al. Epitaxial electrodeposition of chiral metal surfaces on silicon(643). J Am Chem Soc 2018;140:15812–9.
 [9] Brown DA, Morgan S, Peldzinski V, et al. Crystal growth patterns in dc and
- [9] Brown DA, Morgan S, Peldzinski V, et al. Crystal growth patterns in dc and pulsed plated galvanic copper films on (111), (100) and (110) copper surfaces. J Cryst Growth 2017;478:220–8.
- [10] Mayadas AF, Shatzkes M. Electrical-resistivity model for polycrystalline films: the case of arbitrary reflection at external surfaces. Phys Rev B 1970;1:1382–9.
- [11] Zhao YH, Bingert JE, Liao XZ, et al. Simultaneously increasing the ductility and strength of ultra-fine-grained pure copper. Adv Mater 2006;18:2949–53.
- [12] Zhang L, Lu C, Tie AK. Nonlinear elastic response of single crystal cu under uniaxial loading by molecular dynamics study. Mater Lett 2018;227:236–9.
- [13] Hatano T, Kurosawa Y, Miyake J. Effect of material processing on fatigue of FPC rolled copper foil. J Electron Mater 2000;29:611–6.
- [14] Williamson MJ, Tromp RM, Vereecken PM, et al. Dynamic microscopy of nanoscale cluster growth at the solid-liquid interface. Nat Mater 2003;2:532–6.
- [15] Rynders RM, Alkire RC. Use of *in situ* atomic force microscopy to image copper electrodeposits on platinum. J Electrochem Soc 1994;141:1166–73.



Xingguang Li received his B.S. degree from Jinan University in 2014, and his Master's degree from Department of Physics, Renmin University of China in 2019. Currently, he is pursuing a doctor degree in Condensed Matter Physics and Materials Physics at School of Physics, Peking University. His research interest includes electrochemistry and single-crystal metals.



Zhihong Zhang is currently an associate professor at the State Key Laboratory for Advanced Metals and Materials, University of Science and Technology Beijing. She received her Ph.D. degree from Peking University in 2019, followed by postdoctoral research at Peking University. Her main research interest is the controllable growth of single-crystal metal and two-dimensional materials, focusing on surface and interface engineering and growth mechanism exploration.



Enge Wang is currently a chair professor at the International Center for Quantum Materials, School of Physics, Peking University. He received his Ph.D. degree from School of Physics, Peking University in 1990. His current research interest includes the exploration and physical properties of light-element nanomaterials, surface growth dynamics at atomic scale, and the behavior and properties of water in confined systems.



Kaihui Liu is currently a distinguished professor at the State Key Laboratory for Mesoscopic Physics, School of Physics, Peking University. He received his Ph.D. degree from the Institute of Physics, Chinese Academy of Sciences in 2009 and afterward worked as a postdoctoral research fellow at University of California, Berkeley. His current research interest is the growth, characterization, and applications of meter-scale single crystals including copper foils, graphene, and MoS₂.